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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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N-Channel Power MOSFET

700V, 6A, 0.75Ω

FEATURES

- Super-Junction technology
- High performance due to small figure-of-merit
- High ruggedness performance
- High commutation performance

RET PERFURIMANCE PARAIMETERS				
PARAMETER	VALUE UN			
V_{DS}	700	V		
R _{DS(on)} (max)	0.75	Ω		
Q_g	10.7	nC		

Pb





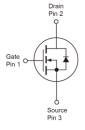
APPLICATION

- Power Supply
- Lighting





TO-252 (DPAK)



Notes: MSL 3 (Moisture Sensitivity Level) for TO-252 (D-PAK) per J-STD-020

ABSOLUTE MAXIMUM RATINGS (T _C = 25°C unless otherwise noted)				
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-Source Voltage		V_{DS}	700	V
Gate-Source Voltage		V_{GS}	±30	V
Continuous Drain Current (Note 1)	$T_C = 25^{\circ}C$	- I _D	6	А
	$T_C = 100$ °C		3.6	
Pulsed Drain Current (Note 2)		I _{DM}	18	Α
Total Power Dissipation @ T _C = 25°C		P _{DTOT}	62.5	W
Single Pulsed Avalanche Energy (Note 3)		E _{AS}	81	mJ
Single Pulsed Avalanche Current (Note 3)		I _{AS}	1.8	А
Operating Junction and Storage Temperatu	re Range	T_J, T_STG	- 55 to +150	°C

THERMAL PERFORMANCE			
PARAMETER	SYMBOL	LIMIT	UNIT
Junction to Case Thermal Resistance	R _{eJC}	2.0	°C/W
Junction to Ambient Thermal Resistance	R _{OJA}	62	°C/W

Notes: $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances. The case thermal reference is defined at the solder mounting surface of the drain pins. $R_{\Theta JA}$ is guaranteed by design while $R_{\Theta CA}$ is determined by the user's board design. $R_{\Theta JA}$ shown below for single device operation on FR-4 PCB in still air.





ELECTRICAL SPECIFICATIONS (T _C = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static (Note 4)						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	BV _{DSS}	700			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	$V_{GS(TH)}$	2	3	4	V
Gate Body Leakage	$V_{GS} = \pm 30V, V_{DS} = 0V$	I _{GSS}			±100	nA
Zero Gate Voltage Drain Current	$V_{DS} = 700V, V_{GS} = 0V$	I _{DSS}			1	μΑ
Drain-Source On-State Resistance	$V_{GS} = 10V, I_D = 1.8A$	R _{DS(on)}		0.62	0.75	Ω
Dynamic (Note 5)						
Total Gate Charge	$V_{DS} = 380V, I_{D} = 6A,$	Q_g		10.7		
Gate-Source Charge		Q_{gs}		2.8		nC
Gate-Drain Charge	$V_{GS} = 10V$	Q_{gd}		3.5		
Input Capacitance	$V_{DS} = 100V, V_{GS} = 0V,$	C _{iss}		555		. =
Output Capacitance	f = 1.0MHz	C _{oss}		39		pF
Gate Resistance	f = 1MHz, open drain	R_g		2.7		Ω
Switching (Note 6)						
Turn-On Delay Time		t _{d(on)}		15		
Turn-On Rise Time	$\begin{split} V_{DD} &= 380 \text{V}, \\ R_{GEN} &= 25 \Omega, \\ I_D &= 6 \text{A}, \ V_{GS} = 10 \text{V}, \end{split}$	t _r		26		
Turn-Off Delay Time		t _{d(off)}		30		ns
Turn-Off Fall Time		t _f		18		
Source-Drain Diode (Note 4)						
Forward On Voltage	I _S = 6A, V _{GS} = 0V	V_{SD}			1.4	V
Reverse Recovery Time	$V_{B} = 200V, I_{S} = 3A$	t _{rr}		182		ns
Reverse Recovery Charge	$dI_F/dt = 100A/\mu s$	Q _{rr}		1.3		μC

Notes:

- 1. Current limited by package
- 2. Pulse width limited by the maximum junction temperature
- 3. L = 50mH, $I_{AS} = 1.8A$, $V_{DD} = 50V$, $R_G = 25\Omega$, Starting $T_J = 25^{\circ}C$
- 4. Pulse test: PW \leq 300 μ s, duty cycle \leq 2%
- 5. For DESIGN AID ONLY, not subject to production testing.
- 6. Switching time is essentially independent of operating temperature.





ORDERING INFORMATION

PART NO.	PACKAGE	PACKING
TSM70N750CH C5G	TO-251 (IPAK)	75pcs / Tube
TSM70N750CP ROG	TO-252 (DPAK)	2,500pcs / 13" Reel

Note:

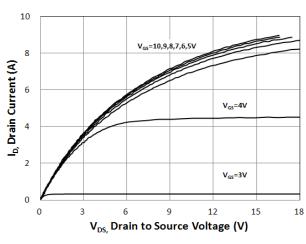
- 1. Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- 2. Halogen-free according to IEC 61249-2-21 definition



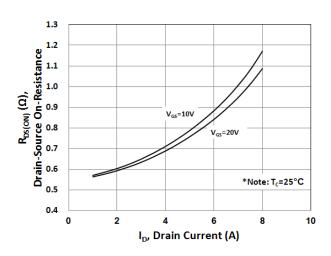
CHARACTERISTICS CURVES

 $(T_C = 25^{\circ}C \text{ unless otherwise noted})$

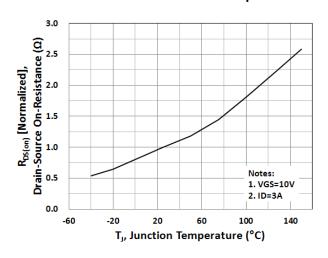
Output Characteristics



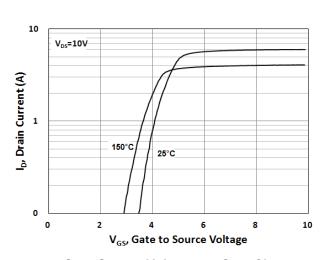
On-Resistance vs. Drain Current



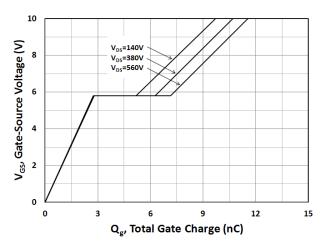
On-Resistance vs. Junction Temperature



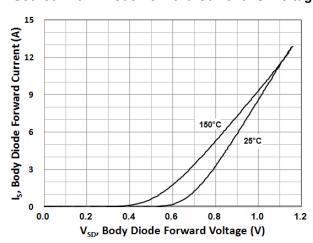
Transfer Characteristics



Gate-Source Voltage vs. Gate Charge



Source-Drain Diode Forward Current vs. Voltage

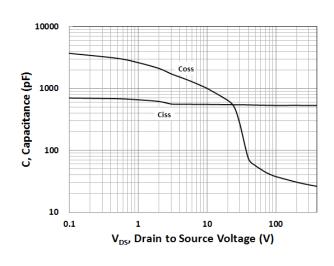




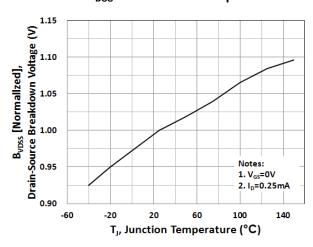
CHARACTERISTICS CURVES

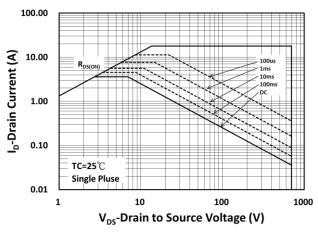
(T_C = 25°C unless otherwise noted)

Capacitance vs. Drain-Source Voltage



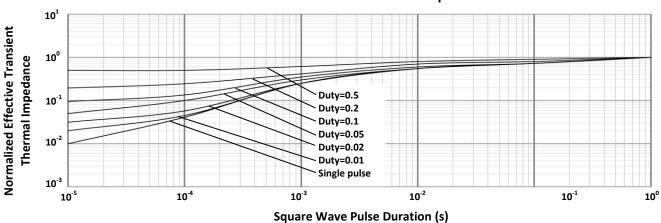
BV_{DSS} vs. Junction Temperature





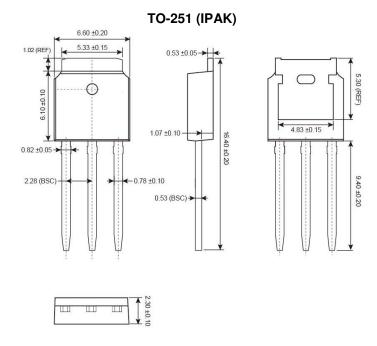
Maximum Safe Operating Area (DPAK/IPAK)

Normalized Thermal Transient Impedance

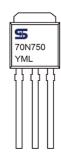




PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)



MARKING DIAGRAM



Y = Year Code

M = Month Code for Halogen Free Product

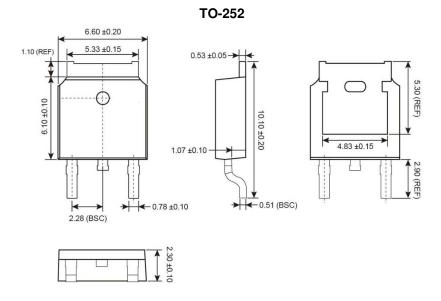
O =Jan P =Feb Q =Mar R =Apr S =May T =Jun U =Jul V =Aug

 \mathbf{W} =Sep \mathbf{X} =Oct \mathbf{Y} =Nov \mathbf{Z} =Dec

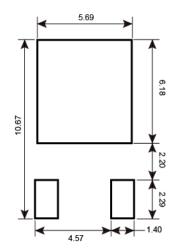
L = Lot Code $(1\sim9, A\sim Z)$



PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)



SUGGESTED PAD LAYOUT (Unit: Millimeters)



MARKING DIAGRAM



Y = Year Code

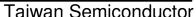
M = Month Code for Halogen Free Product

O =Jan P =Feb Q =Mar R =Apr

S =May T =Jun U =Jul V =Aug

 $W = Sep \quad X = Oct \quad Y = Nov \quad Z = Dec$

L = Lot Code $(1\sim9, A\sim Z)$





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